

FEATURES

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IXTH450P2

· Drain Source Voltage-: V_{DSS}= 500V(Min) Static Drain-Source On-Resistance : R_{DS(on)} = 330m Ω (Max) Fast Switching • 100% avalanche tested · Minimum Lot-to-Lot variations for robust device performance and reliable operation APPLICATIONS · Switch-Mode and Resonant-Mode Power Supplies DC-DC Converters

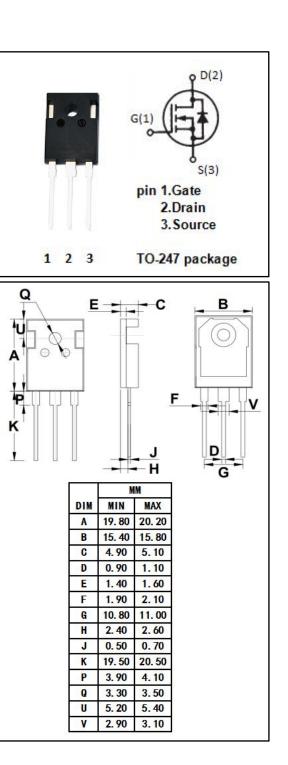
- AC and DC Motor Drives
- · Robotics and Servo Controls

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	500	V
V _{GS}	Gate-Source Voltage-Continuous	±30	V
ID	Drain Current-Continuous	16	А
I _{DM}	Drain Current-Single Plused 48		А
P _D	Total Dissipation @T _c =25℃ 300		W
Tj	Max. Operating Junction Temperature	-55~150	°C
T _{stg}	Storage Temperature	-55~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.42	°C/W



isc website: <u>www.iscsemi.com</u>



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• ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D =250µA	500			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =250uA	2.5		4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 8A			330	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±30V;V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =500V; V _{GS} = 0 V _{DS} =500V; V _{GS} = 0;TJ=125°C			5 25	μA
V _{SD}	Diode Forward On-voltage	IF= 16A;V _{GS} = 0			1.3	V

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